







60V NPN MEDIUM POWER TRANSISTOR PowerDI[®]5

Features

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 3.2W
- $V_{CEO} = 60V$
- $I_C = 6A$; $I_{CM} = 20A$
- Low Saturation voltage
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Applications

- Motor driver
- Regulator circuit

Mechanical Data

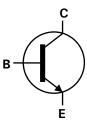
- Case: PowerDI®5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.093 grams (approximate)



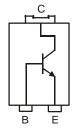




Bottom View



Device Schematic



Pin-out diagram

Ordering Information (Note 3)

Part Number	Case	Packaging
DXT2010P5-13	PowerDI [®] 5	5000/Tape & Reel

Notes:

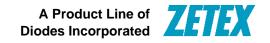
- 1. No purposefully added lead. Halogen and Antimony Free.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



DXT2010 = Product Type Marking Code Oll = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 09 for 2009) WW = Week code (01 to 53)





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	150	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	lc	6	A
Peak Pulse Current	I _{CM}	20	A

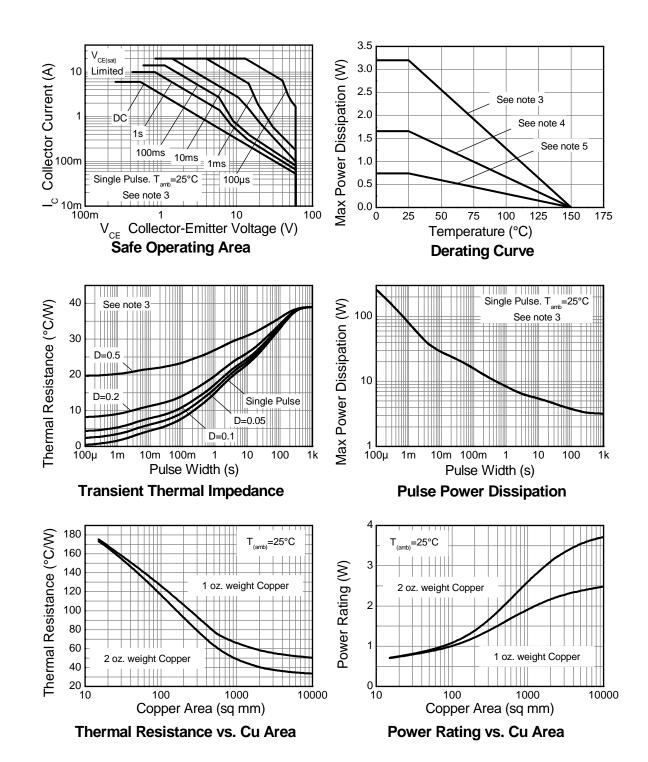
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 4)	P_{D}	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 4) @T _A = 25°C	$R_{\theta JA}$	39	°C/W
Power Dissipation @ T _A = 25°C (Note 5)	P _D	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 5) @T _A = 25°C	$R_{\theta JA}$	75	°C/W
Power Dissipation @ T _A = 25°C (Note 6)	P_{D}	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 6) @T _A = 25°C	$R_{\theta JA}$	169	°C/W
Thermal Resistance, Junction to Collector Terminal	$R_{ heta JT}$	5.6	°C/W
Operating and Storage Temperature Range	T_J,T_STG	-55 to +150	°C

Notes:

- Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 25mm x 25mm.
 Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 50mm x 50mm.
 Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.





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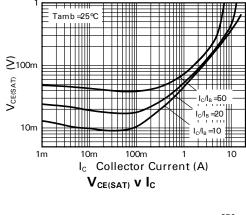
Electrical Characteristics @T_A = 25°C unless otherwise specified

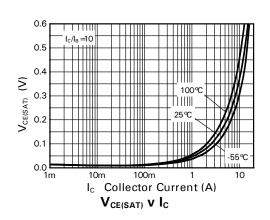
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	150	190	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 7)	V _{(BR)CEO}	60	80	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	7.0	8.1	_	V	$I_E = 100 \mu A$
Collector Cutoff Current	lose	_		20	nA	V _{CB} = 120V
Collector Catoli Carrent	I _{CBO}			0.5	μΑ	V _{CB} = 120V, T _{amb} = 100 °C
Collector Cutoff Current	ICER		_	20	nA	V _{CB} = 120V
Concessor Cuton Current	R≤1kΩ			0.5	μΑ	V _{CB} = 120V, T _{amb} = 100 °C
Emitter Cutoff Current	I _{EBO}	_	_	10	nA	$V_{EB} = 6V$
			20	30		$I_C = 100 \text{mA}, I_B = 5 \text{mA}$
			45	60	mV	$I_C = 1A$, $I_B = 100mA$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}		50	70		$I_C = 1A$, $I_B = 50mA$
			100	135		$I_C = 2A$, $I_B = 50mA$
			210	260		$I_C = 6A, I_B = 300mA$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	_	1000	1100	mV	$I_C = 6A$, $I_B = 300mA$
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	_	940	1050	mV	$V_{CE} = 1V, I_{C} = 6A$
		100	200			$I_C = 10mA$, $V_{CE} = 1V$
DC Current Gain (Note 6)	h	100	200	300		$I_C = 2A$, $V_{CE} = 1V$
DC Current Gain (Note o)	h _{FE}	55 20	105	_	_	$I_C = 5A$, $V_{CE} = 1V$
			40	_		$I_C = 10A$, $V_{CE} = 1V$
Transition Frequency	++	_	130	_	MHz	$I_C = 100 \text{mA}, \ V_{CE} = 10 \text{V}$
<u> </u>	f⊤					f = 50MHz
Output Capacitance (Note 7)	C _{obo}	_	31	_	pF	$V_{CB} = -10A$, $f = 1MHz$
Switching Times	t _{on}	_	42	_	ns	$I_C = 1A$, $V_{CC} = 10V$,
Ownorming Times	t _{off}	_	760	_	ns	$I_{B1} = I_{B2} = 100 \text{mA}$

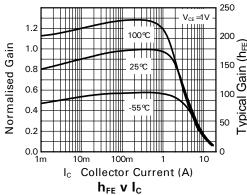
Notes: 7. Pulse Test: Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2.0\%$.

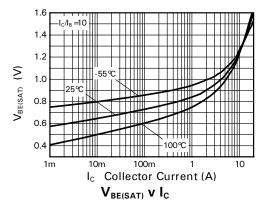


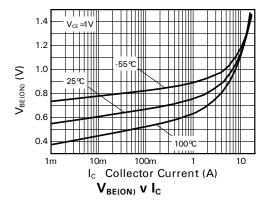
Typical Characteristic







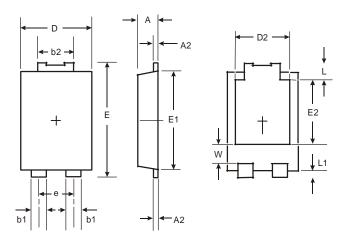






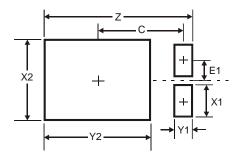


Package Outline Dimensions



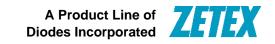
PowerDI [®] 5				
Dim	Min	Max		
Α	1.05	1.15		
A2	0.33	0.43		
b1	0.80	0.99		
b2	1.70	1.88		
D	3.90	4.05		
D2	3.054 Typ			
Е	6.40	6.60		
е	1.84 Typ			
E1	5.30	5.45		
E2	3.549 Typ			
L	0.75	0.95		
L1	0.50	0.65		
W	1.10	1.41		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
С	3.87
F1	0.9





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